### TOSHIBA PHOTOCOUPLER PHOTO RELAY

## **TLP227A,TLP227A-2**

# CORDLESS TELEPHONE PBX MODEM

The TOSHIBA TLP227A series consist of a gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a plastic DIP package.

The TLP227A series are a bi-directional switch, which can replace mechanical relays in many applications.

### **Features**

• TLP227A : 4 pin DIP (DIP4)

1 Channel Type (1 Form A)

• TLP227A-2 : 8 pin DIP (DIP8)

2 Channel Type (2 Form A)

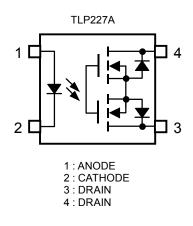
Peak Off-State Voltage : 60 V (MIN.)
 Trigger LED Current : 3 mA (MAX.)
 On-State Current : 500 mA (MAX.)
 On-State Resistance : 2 Ω (MAX.)
 Isolation Voltage : 2500 Vrms (MIN.)

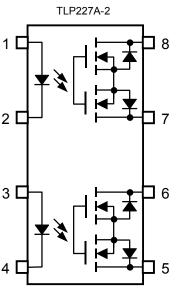
• UL Recognized : UL1577, File No. E67349

# Unit: mm TLP227A 4 3 4 3 7 62±0.25 1.2±0.15 0.5±0.1 E 2.54±0.25 7.62±0.25 7.62±0.25 7.85~8.80 JEDEC EIAJ TOSHIBA 11–5B2

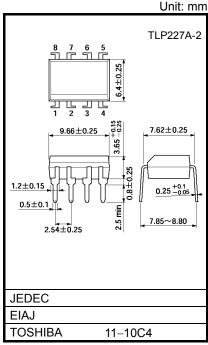
Weight: 0.26 g

### Pin Configuration (top view)





1, 3 : ANODE 2, 4 : CATHODE 5 : DRAIN D1 6 : DRAIN D2 7 : DRAIN D3 8 : DRAIN D4



Weight: 0.54 g



### Absolute Maximum Ratings (Ta = 25°C)

	CHARACTE	SYMBOL	RATING	UNIT		
	Forward Current	lF	50	mA		
	Forward Current Derating (Ta ≧ 25°C)	ΔI <sub>F</sub> /°C	-0.5	mA/°C		
LED	Peak Forward Current (100µs pulse, 10	0 pps)		IFP	1	Α
	Reverse Voltage	V <sub>R</sub>	5	V		
	Junction Temperature	Tj	T <sub>j</sub> 125			
	Off-State Output Terminal Voltage	V <sub>OFF</sub>	60	V		
	On-State Current	TLP227A				
8		TLP227A-2	One Channel	I <sub>ON</sub>	500	mA
STC			Both Channel (Note 1)			
DETECTOR	On-State Current Derating (Ta ≧ 25°C)	TLP227A				
B		TI D0074 0	One Channel	Δl <sub>ON</sub> /°C	-5.0	mA/°C
		TLP227A-2	Both Channel (Note 1)			
	Junction Temperature	Tj	125	°C		
Stora	ge Temperature Range	T <sub>stg</sub>	<b>−55~125</b>	°C		
Operating Temperature Range				T <sub>opr</sub>	<b>−40~85</b>	°C
Lead	Soldering Temperature (10 s)	T <sub>sol</sub>	260	°C		
Isolat	ion Voltage (AC, 1 minute, R.H. ≦ 60%)	BV <sub>S</sub> 2500		Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1): Two channels operating simultaneously.

(Note 2):Device considered a two-terminal device : LED side pins shorted together, and DETECTOR side pins shorted together.

### **Recommended Operating Conditions**

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V_{DD}$	_	_	48	V
Forward Current	lF	5	7.5	25	mA
On-State Current	I <sub>ON</sub>	_	_	400	mA
Operating Temperature	T <sub>opr</sub>	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

### Individual Electrical Characteristics (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
E	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μА
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
DETECTOR	Off-State Current	l <sub>OFF</sub>	V <sub>OFF</sub> = 60 V			1	μА
	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz		130		pF

### **Coupled Electrical Characteristics (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I <sub>FT</sub>	I <sub>ON</sub> = 300 mA	_	1	3	mA
Close LED Current	I <sub>FC</sub>	I <sub>OFF</sub> = 100 μA	0.1	_	_	mA
On-State Resistance	R <sub>ON</sub>	$I_{ON} = 300 \text{ mA}, I_F = 5 \text{ mA}$	_	1	2	Ω

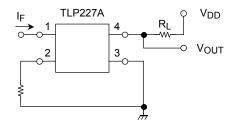
### **Isolation Characteristics (Ta = 25°C)**

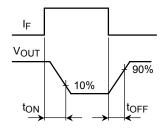
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	Cs	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation Resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≦ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation Voltage		AC, 1 second (in oil)	_	5000	_	
		DC, 1 minute (in oil)	_	5000	_	Vdc

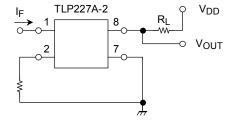
### **Switching Characteristics (Ta = 25°C)**

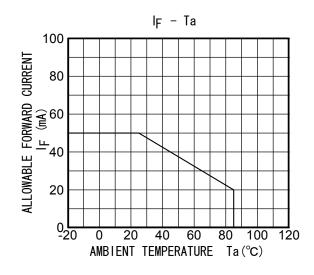
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t <sub>ON</sub>	$R_L = 200 \Omega$	_	0.6	2	ms
Turn-off Time	toff	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note 3)		0.1	1	1115
Turn-on Time	toN	$R_L = 200 \Omega$	_	0.3	1	ms
Turn-off Time	t <sub>OFF</sub>	$V_{DD} = 20 \text{ V}, I_F = 10 \text{ mA}$ (Note 3)	_	0.1	1	1115

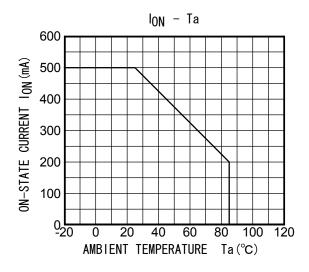
(Note 3): SWITCHING TIME TEST CIRCUIT

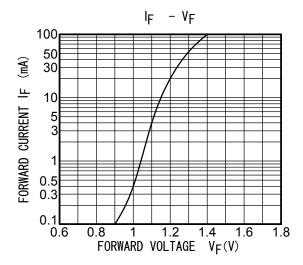


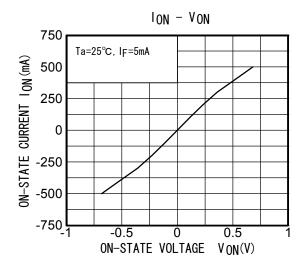


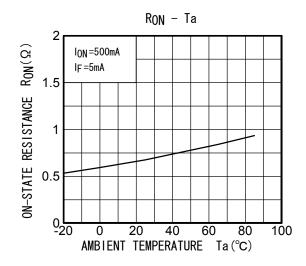


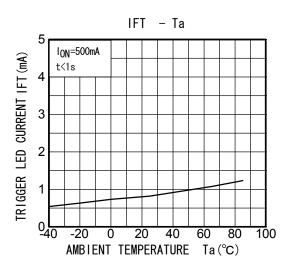


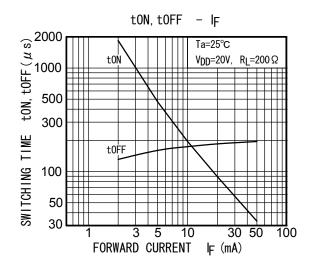


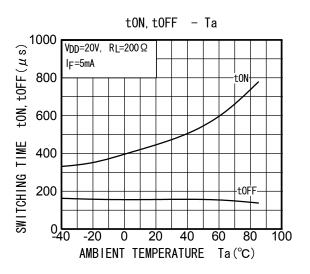


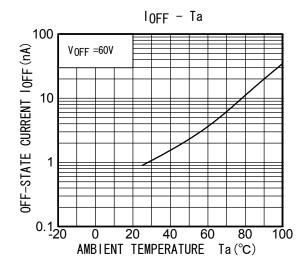












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